Report of Experiment 25-01-794

"The influence of MnN_x in the electrical and optical properties of Si_3N_4 : XAS study at the Mn K-edge"

Experimental: XANES and EXAFS (k = 12) in fluorescence detection mode. Angle x-ray beam-detector of 90°; beam-sample 30° aprox.

Measured samples:

- Mn foil (transmission)
- $[MnN_{x(1.5 nm)}/Si_3N_{4(3nm)}]_{10}$ samples with P_{N2}/P_{total} ratio of: 0%, 25%, 50%, 75%, 100% (20 bilayers) and also Mn/Si_3N_4 (1 Mn layer with 3nm of Si_3N_4 on top, named as MnSN0)

The normalized sample spectra are shown in Fig. 1.



Fig. 1. Normalized sample spectra. A zoom of the pre-peak region is shown in the inset of Fig1 (a). Fig 1(b) exhibits the differences between $[MnN_{x(1.5 nm)}/Si_3N_{4(3nm)}]_{10}$ samples with P_{N2}/P_{total} ratio of 25% and 100%.

First analysis shows that, except for MnSN0 sample, with mostly metallic Mn, just slight differences appear in the XAS spectra of $[MnN_{x(1.5 nm)}/Si_3N_{4(3nm)}]_{10}$ samples prepared with different P_{N2}/P_{total} ratio.

The XANES region of $[MnN_{x(1.5 nm)}/Si_3N_{4(3nm)}]_{10}$ sample prepared with 0% of N_2 (black line) presents some differences respect to the others, as enhanced white line intensity, increased XAS features amplitude and different evolution of the pre-peak intensity in comparison with the other samples from the series, as it can be observed in Fig 1(a).

Despite the slight differences, a direct relation seems to appear between the optical and electrical properties of the samples series and their XAS spectra.

Clear differences can be observed in the pre-peak intensity. Samples prepared with 25 % and 50 % of P_{N2}/P_{total} show reduced and nearly identical pre-peak amplitude, in agreement with their enhanced and similar resistivity values. By contrast, the samples prepared with 75 % and 50 % of P_{N2}/P_{total} show an increased pre-peak intensity, what can be related to their smaller electric resistivity, decreasing the electrical resistivity as the pre-peak intensity increases.

Sample prepared with 0% of N_2 , on the other hand, exhibits different XAS features. However, its pre-peak intensity follows the same evolution as the electric resistivity, laying between samples with 75 % and 50 %.

Fig 1(b) exhibits the differences between $[MnN_{x(1.5 nm)}/Si_3N_{4(3nm)}]_{10}$ samples with P_{N2}/P_{total} ratio of 25% and 100 %.